

IRF3710PBF

Request a Quote

IRF3710PBF Information

www.elspher.com	Part Number	IRF3710PBF
	Manufacturer	Infineon Technologies
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
	Description	MOSFET N-CH 100V 57A TO-220AB
	Package	TO-220-3
		For the pricing/inventory/lead time, please contact
For Reference Only		us
		Website: https://www.heisener.com
		E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRF3710PBF Specifications

Manufacturer Part Number	IRF3710PBF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	ТО-220-3
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	57A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	130nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3130pF @ 25V
Vgs (Max)	$\pm 20 \mathrm{V}$
FET Feature	-
Power Dissipation (Max)	200W (Tc)
Rds On (Max) @ Id, Vgs	23 mOhm @ 28A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	ТО-220-3
	Report errors?

IRF3710PBF Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

If you have any question about IRF3710PBF, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com